

# MJ15003 (NPN), MJ15004 (PNP)

Preferred Device

## Complementary Silicon Power Transistors

The MJ15003 and MJ15004 are PowerBase™ power transistors designed for high power audio, disk head positioners and other linear applications.

### Features

- High Safe Operating Area (100% Tested) – 5.0 A @ 50 V
- For Low Distortion Complementary Designs
- High DC Current Gain –  $h_{FE} = 25$  (Min) @  $I_C = 5$  Adc
- Pb-Free Packages are Available\*

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	140	Vdc
Collector-Base Voltage	$V_{CBO}$	140	Vdc
Emitter-Base Voltage	$V_{EBO}$	5	Vdc
Collector Current – Continuous	$I_C$	20	Adc
Base Current – Continuous	$I_B$	5	Adc
Emitter Current – Continuous	$I_E$	25	Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	250 1.43	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.70	$^\circ\text{C}/\text{W}$
Maximum Lead Temperature for Soldering Purposes 1/16" from Case for $\leq 10$ secs	$T_L$	265	$^\circ\text{C}$

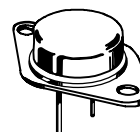
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



ON Semiconductor®

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**20 AMPERE  
POWER TRANSISTORS  
COMPLEMENTARY SILICON  
140 VOLTS, 250 WATTS**



TO-204AA (TO-3)  
CASE 1-07  
STYLE 1

### MARKING DIAGRAM



MJ1500x = Device Code  
x = 3 or 4  
G = Pb-Free Package  
A = Location Code  
YY = Year  
WW = Work Week  
MEX = Country of Origin

### ORDERING INFORMATION

Device	Package	Shipping
MJ15003	TO-204AA	100 Units/Tray
MJ15003G	TO-204AA (Pb-Free)	100 Units/Tray
MJ15004	TO-204AA	100 Units/Tray
MJ15004G	TO-204AA (Pb-Free)	100 Units/Tray

Preferred devices are recommended choices for future use and best overall value.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MJ15003 (NPN), MJ15004 (PNP)

## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector Emitter Sustaining Voltage (Note 1) ( $I_C = 200\text{ mAdc}$ , $I_B = 0$ )	$V_{CE(sus)}$	140	–	Vdc
Collector Cutoff Current ( $V_{CE} = 140\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ ) ( $V_{CE} = 140\text{ Vdc}$ , $V_{BE(off)} = 1.5\text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )	$I_{CEX}$	–	100 2	$\mu\text{Adc}$ mAdc
Collector Cutoff Current ( $V_{CE} = 140\text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	–	250	$\mu\text{Adc}$
Emitter Cutoff Current ( $V_{EB} = 5\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	100	$\mu\text{Adc}$
<b>SECOND BREAKDOWN</b>				
Second Breakdown Collector Current with Base Forward Biased ( $V_{CE} = 50\text{ Vdc}$ , $t = 1\text{ s}$ (non repetitive)) ( $V_{CE} = 100\text{ Vdc}$ , $t = 1\text{ s}$ (non repetitive))	$I_{S/b}$	5.0 1.0	– –	Adc
<b>ON CHARACTERISTICS</b>				
DC Current Gain ( $I_C = 5\text{ Adc}$ , $V_{CE} = 2\text{ Vdc}$ )	$h_{FE}$	25	150	–
Collector Emitter Saturation Voltage ( $I_C = 5\text{ Adc}$ , $I_B = 0.5\text{ Adc}$ )	$V_{CE(sat)}$	–	1.0	Vdc
Base Emitter On Voltage ( $I_C = 5\text{ Adc}$ , $V_{CE} = 2\text{ Vdc}$ )	$V_{BE(on)}$	–	2.0	Vdc
<b>DYNAMIC CHARACTERISTICS</b>				
Current Gain — Bandwidth Product ( $I_C = 0.5\text{ Adc}$ , $V_{CE} = 10\text{ Vdc}$ , $f_{test} = 0.5\text{ MHz}$ )	$f_T$	2.0	–	MHz
Output Capacitance ( $V_{CB} = 10\text{ Vdc}$ , $I_E = 0$ , $f_{test} = 1\text{ MHz}$ )	$C_{ob}$	–	1000	pF

1. Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

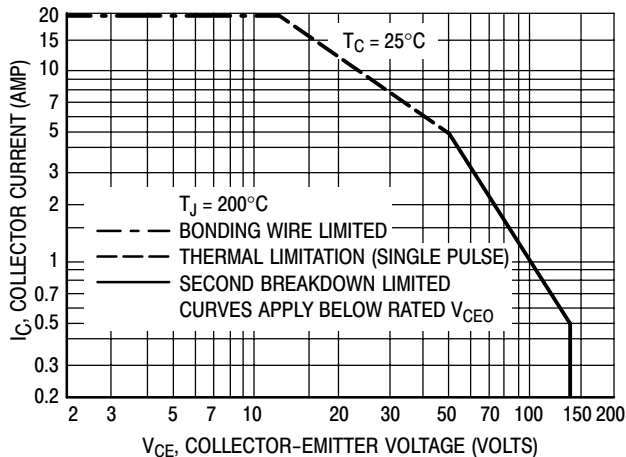


Figure 1. Active-Region Safe Operating Area

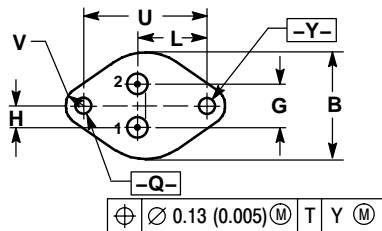
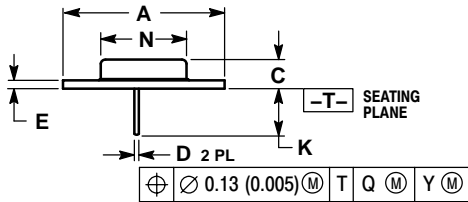
There are two limitations on the powerhandling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 1 is based on  $T_{J(pk)} = 200^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

# MJ15003 (NPN), MJ15004 (PNP)

## PACKAGE DIMENSIONS

TO-204 (TO-3)  
CASE 1-07  
ISSUE Z



NOTES:


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO-204AA OUTLINE SHALL APPLY.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:

- PIN 1. BASE
  - EMITTER
- CASE: COLLECTOR

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